

BC807-Q series

45 V, 500 mA PNP general-purpose transistors Rev. 1 — 4 June 2021

Product data sheet

1. General description

PNP general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	NPN complement		
	Nexperia	JEDEC	JEITA	
BC807-Q	SOT23	TO-236AB -	-	BC817-Q
BC807-16-Q				BC817-16-Q
BC807-25-Q				BC817-25-Q
BC807-40-Q				BC817-40-Q

2. Features and benefits

- High current
- Three current gain selections
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	-45	V
Ic	collector current	T _{amb} = 25 °C		-	-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	-1	Α
h _{FE}	DC current gain					•	
	BC807-Q	V _{CE} = -1 V; I _C = -100 mA T _{amb} = 25 °C	[1]	100	-	600	
	BC807-16-Q		[1]	100	-	250	
	BC807-25-Q		[1]	160	-	400	
	BC807-40-Q		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	C
2	E	emitter		B—
3	С	collector		, h
				E sym132
			1	

6. Ordering information

Table 4. Ordering information

Tubio 4. Oracini	table 4. Grading information								
Type number	Package	Package							
	Name	Description	Version						
BC807-Q	TO-236AB	Plastic surface-mounted package; 3 leads	SOT23						
BC807-16-Q									
BC807-25-Q									
BC807-40-Q									

7. Marking

Table 5. Marking

Type number	Marking code[1]
BC807-Q	5D%
BC807-16-Q	5A%
BC807-25-Q	5B%
BC807-40-Q	5C%

[1] % = placeholder for manufacturing site code

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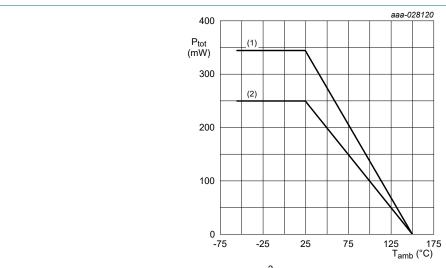
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	-	-50	V
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C	-	-45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C	-	-5	V
Ic	collector current	T _{amb} = 25 °C	-	-500	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1$ ms; $T_{amb} = 25$ °C	-	-1	А
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	-	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$ [1]		250	mW
		[3 [2	-	345	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	150	°C
T _{stg}	storage temperature		-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm₂.



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

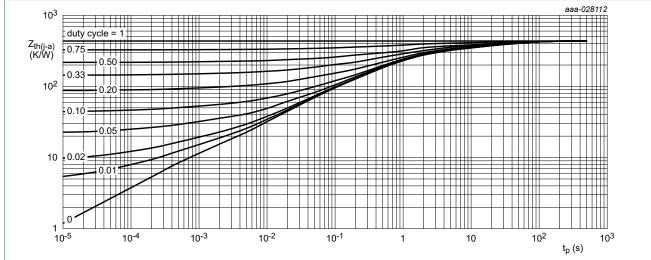
Fig. 1. Power derating curves for SOT23

9. Thermal characteristics

Table 7. Thermal characteristics

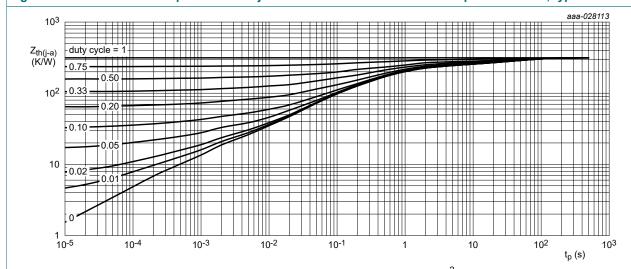
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W
			[3] [2]	-	-	362	K/W

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

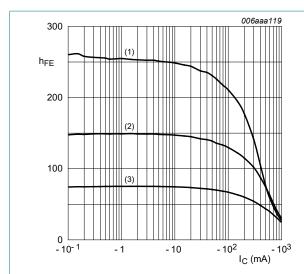
Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 8. Characteristics

Parameter	Conditions		Min	Тур	Max	Unit
collector-base breakdown voltage	$I_C = -100 \ \mu\text{A}; \ I_E = 0 \ \text{A}; \ T_{amb} = 25 \ ^{\circ}\text{C}$		-50	-	-	V
collector-emitter breakdown voltage	I_{C} = -10 mA; I_{E} = 0 A; T_{amb} = 25 °C		-45	-	-	V
emitter-base breakdown voltage	$I_E = -100 \ \mu A; \ I_C = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$		-5	-	-	V
collector-base	V _{CB} = -20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
cut-off current	$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	-5	μA
emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
DC current gain			'		'	_
BC807-Q	V _{CE} = -1 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	100	-	600	
BC807-16-Q		[1]	100	-	250	
BC807-25-Q		[1]	160	-	400	
BC807-40-Q		[1]	250	-	600	
DC current gain	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	40	-	-	
collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	-700	mV
base-emitter voltage	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1] [2]	-	-	-1.2	V
transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz; T _{amb} = 25 °C		80	-	-	MHz
collector capacitance	V_{CB} = -10 V; I_{E} = I_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	5	-	pF
	collector-base breakdown voltage collector-emitter breakdown voltage emitter-base breakdown voltage collector-base cut-off current emitter-base cut-off current DC current gain BC807-Q BC807-16-Q BC807-25-Q BC807-40-Q DC current gain collector-emitter saturation voltage base-emitter voltage	collector-base breakdown voltage	collector-base breakdown voltage $I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ collector-emitter breakdown voltage $I_C = -10 \text{mA}; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ emitter-base breakdown voltage $I_E = -100 \mu A; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ collector-base cut-off current $V_{CB} = -20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ emitter-base cut-off current $V_{CB} = -20 V; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ DC current gain $V_{CE} = -1 V; I_C = -100 \text{mA}; T_{amb} = 25 ^{\circ}C$ BC807-Q $V_{CE} = -1 V; I_C = -100 \text{mA}; T_{amb} = 25 ^{\circ}C$ BC807-16-Q [1] BC807-40-Q [1] DC current gain $V_{CE} = -1 V; I_C = -500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] collector-emitter saturation voltage $I_C = -500 \text{mA}; I_B = -50 \text{mA}; T_{amb} = 25 ^{\circ}C$ base-emitter voltage $V_{CE} = -1 V; I_C = -500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] transition frequency $V_{CE} = -5 V; I_C = -10 \text{mA}; f = 100 \text{MHz}; T_{amb} = 25 ^{\circ}C$ collector capacitance $V_{CB} = -10 V; I_E = i_e = 0 A; f = 1 \text{MHz};$	collector-base breakdown voltage $I_C = -100 \mu\text{A}$; $I_E = 0 \text{A}$; $T_{amb} = 25 ^{\circ}\text{C}$ -50 collector-emitter breakdown voltage $I_C = -10 \text{mA}$; $I_E = 0 \text{A}$; $T_{amb} = 25 ^{\circ}\text{C}$ -45 emitter-base breakdown voltage $I_E = -100 \mu\text{A}$; $I_C = 0 \text{A}$; $T_{amb} = 25 ^{\circ}\text{C}$ -5 collector-base cut-off current $V_{CB} = -20 \text{V}$; $I_E = 0 \text{A}$; $T_{amb} = 25 ^{\circ}\text{C}$ - emitter-base cut-off current $V_{EB} = -5 \text{V}$; $I_C = 0 \text{A}$; $V_{EB} = 0 \text{A}$; V_{E	collector-base breakdown voltage $I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ -50 -50 collector-emitter breakdown voltage $I_C = -10 mA; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ -45 -50 collector-base breakdown voltage $I_E = -100 \mu A; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ -5 collector-base cut-off current $V_{CB} = -20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CB} = -20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CB} = -20 V; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CB} = -5 V; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -100 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -100 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -100 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -1 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -5 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -5 V; I_C = -500 mA; T_{amb} = 25 ^{\circ}C$ -5 cut-off current $V_{CE} = -5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA; T_{amb} = 25 ^{\circ}C$ $-5 V; I_C = -10 mA$	collector-base breakdown voltage $I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ -50 - collector-emitter breakdown voltage $I_C = -10 \text{mA}; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ -45 - emitter-base breakdown voltage $I_E = -100 \mu A; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ -5 - collector-base cut-off current $V_{CB} = -20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ - - -100 emitter-base cut-off current $V_{CB} = -20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ - - -5 emitter-base cut-off current $V_{CB} = -5 V; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ - - -100 DC current gain $V_{CE} = -1 V; I_C = -100 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] $100 - 000$ 600 BC807-16-Q BC807-25-Q [1] $160 - 400$ [1] $160 - 400$ BC807-40-Q $V_{CE} = -1 V; I_C = -500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] $100 - 500$ DC current gain $V_{CE} = -1 V; I_C = -500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] $- - -700$ base-emitter voltage $V_{CE} = -1 V; I_C = -500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] $- - -1.2$ transition frequency<

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu \text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$



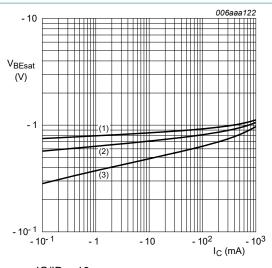
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC807-16-Q: DC current gain as a function of collector current; typical values

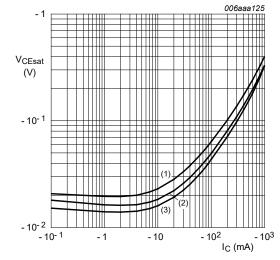


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC807-16-Q: Base-emitter saturation voltage as a function of collector current; typical values



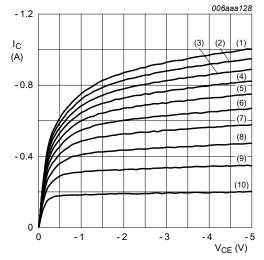
$$IC/IB = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC807-16-Q: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = -16.0 \text{ mA}$$

(2)
$$I_B = -14.4 \text{ mA}$$

(3)
$$I_B = -12.8 \text{ mA}$$

$$(4) I_B = -11.2 \text{ mA}$$

$$(5) I_B = -9.6 \text{ mA}$$

(6)
$$I_B = -8.0 \text{ mA}$$

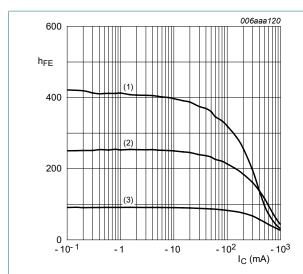
$$(7) I_B = -6.4 \text{ mA}$$

$$(8) I_B = -4.8 \text{ mA}$$

(9)
$$I_B = -3.2 \text{ mA}$$

$$(10) I_B = -1.6 \text{ mA}$$

Fig. 7. BC807-16-Q: Collector current as a function of collector-emitter voltage; typical values



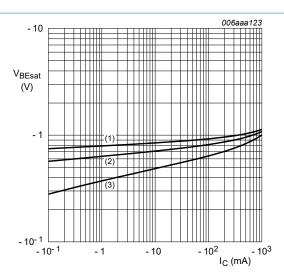
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC807-25-Q: DC current gain as a function of collector current; typical values



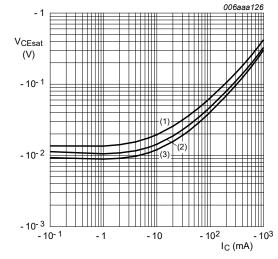
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

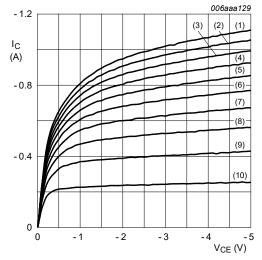
Fig. 9. BC807-25-Q: Base-emitter saturation voltage as a function of collector current; typical values



(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC807-25-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -13.0 \text{ mA}$$

(2)
$$I_B = -11.7 \text{ mA}$$

(3)
$$I_B = -10.4 \text{ mA}$$

$$(4) I_B = -9.1 mA$$

$$(5) I_B = -7.8 \text{ mA}$$

(6)
$$I_B = -6.5 \text{ mA}$$

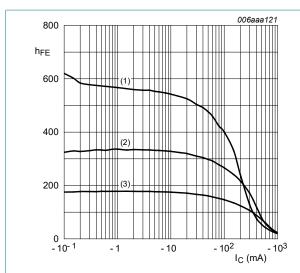
$$(7) I_B = -5.2 \text{ mA}$$

(8)
$$I_B = -3.9 \text{ mA}$$

(9)
$$I_B = -2.6 \text{ mA}$$

$$(10) I_B = -1.3 \text{ mA}$$

Fig. 11. BC807-25-Q: Collector current as a function of collector-emitter voltage; typical values



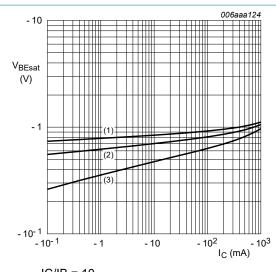
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC807-40-Q: DC current gain as a function of collector current; typical values



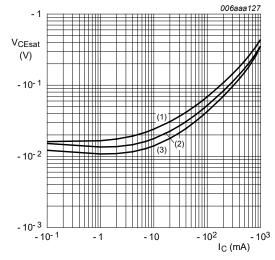
$$IC/IB = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. BC807-40-Q: Base-emitter saturation voltage as a function of collector current; typical values

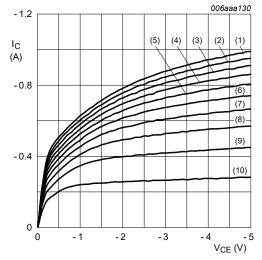


$$IC/IB = 10$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 14. BC807-40-Q: Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -12.0 \text{ mA}$$

$$(2) I_B = -10.8 \text{ mA}$$

$$(3) I_B = -9.6 \text{ mA}$$

$$(4) I_B = -8.4 \text{ mA}$$

(5)
$$I_B = -7.2 \text{ mA}$$

(6)
$$I_B = -6.0 \text{ mA}$$

(7)
$$I_B = -4.8 \text{ mA}$$

(8)
$$I_B = -3.6 \text{ mA}$$

(9)
$$I_B = -2.4 \text{ mA}$$

$$(10) I_B = -1.2 mA$$

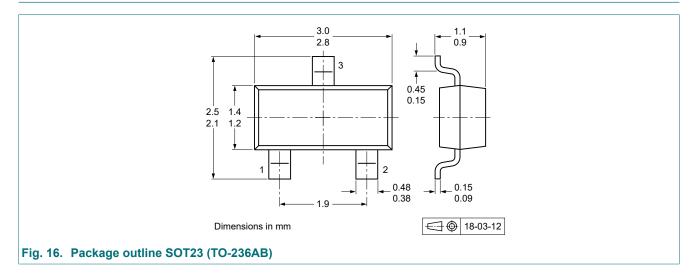
Fig. 15. BC807-40-Q: Collector current as a function of collector-emitter voltage; typical values

11. Test information

11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

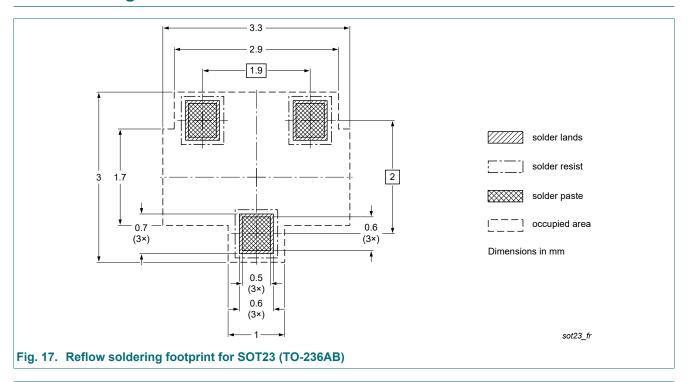
12. Package outline

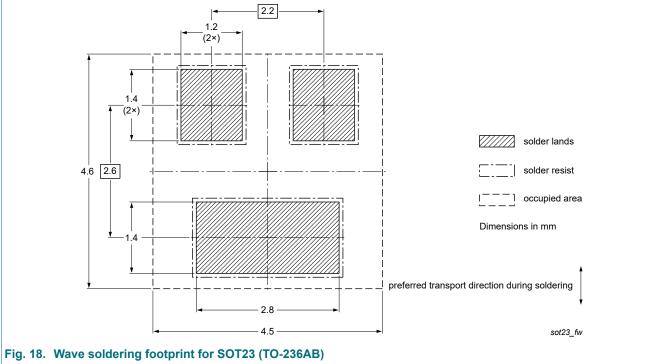


Nexperia BC807-Q series

45 V, 500 mA PNP general-purpose transistors

13. Soldering





Nexperia BC807-Q series

45 V, 500 mA PNP general-purpose transistors

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC807-Q_SER v.1	20210608	Product data sheet	-	-

Nexperia BC807-Q series

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

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45 V, 500 mA PNP general-purpose transistors

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